# 1.0 ELECTRICAL CHARACTERISTICS

# Absolute Maximum Ratings (†)

Vcc	6.5V
All inputs and outputs w.r.t. Vss	-0.6V to Vcc +1.0V
Storage temperature	65°C to +150°C
Ambient temperature under bias	-40°C to +125°C
ESD protection on all pins	

**† NOTICE:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for an extended period of time may affect device reliability.

DC CHA	RACTER	ISTICS	Industrial (I): $TA = -40^{\circ}C$ to $+85^{\circ}C$ Vcc = 1.8V to 5.5V Extended (E): $TA = -40^{\circ}C$ to $+125^{\circ}C$ Vcc = 1.8V to 5.5V			
Param. No. Symbol Characteristic			Minimum	Maximum	Units	Test Conditions
D001	Vih	High-Level Input Voltage	0.7 Vcc	Vcc +1	V	
D002	VIL	Low-Level Input Voltage	-0.3	0.3 Vcc	V	$Vcc \ge 2.5V$
D003	VIL	Low-Level Input voltage	-0.3	0.2 Vcc	V	Vcc < 2.5V
D004	Vol	Low-Level Output	—	0.4	V	IOL = 2.1 mA, VCC = 4.5V
D005	Vol	Voltage	—	0.2	V	IOL = 1.0 mA, VCC = 2.5V
D006	Vон	High-Level Output Voltage	Vcc -0.5	—	V	Іон = -400 μА
D007	Iц	Input Leakage Current	—	±1	μA	CS = Vcc, VIN = Vss or Vcc
D008	Ilo	Output Leakage Current	_	±1	μA	CS = Vcc, Vout = Vss or Vcc
D009	CINT	Internal Capacitance (All Inputs and Outputs)	—	7	pF	TA = 25°C, FCLK = 1.0 MHz, Vcc = 5.0V (Note 2)
D010	Icc		—	6	mA	Vcc = 5.5V; FcLк = 10.0 MHz; SO = Open
DUTU	Read	l Operating Current	—	2.5	mA	Vcc = 2.5V; FcLк = 5.0 MHz; SO = Open
D011	Icc		—	5	mA	Vcc = 5.5V
DOTI	Write		—	3	mA	Vcc = 2.5V
D012		Standby Current	—	5	μA	$\overline{CS}$ = Vcc = 5.5V, Inputs tied to Vcc or Vss, +125°C
0012	Iccs	Standby Current	—	1	μA	CS = Vcc = 5.5V, Inputs tied to Vcc or Vss, +85°C

#### TABLE 1-1: DC CHARACTERISTICS

Note 1: Typical measurements taken at room temperature (+25 $^{\circ}$ C).

2: This parameter is periodically sampled and not 100% tested.

AC CHA	RACTER	ISTICS	Industrial (I): $TA = -40^{\circ}C$ to $+85^{\circ}C$ Vcc = 1.8V to 5.5V Extended (E): $TA = -40^{\circ}C$ to $+125^{\circ}C$ Vcc = 1.8V to 5.5V				
Param. No.	Symbol	Characteristic	Minimum	Maximum	Units	Test Conditions	
			—	10	MHz	$4.5V \leq Vcc \leq 5.5V$	
1 FCLK Clock Frequency		Clock Frequency	—	5	MHz	$2.5V \leq Vcc < 4.5V$	
		—	3	MHz	$1.8V \leq Vcc < 2.5V$		
			50	_	ns	$4.5V \leq Vcc \leq 5.5V$	
2	Tcss	CS Setup Time	100	—	ns	$2.5V \leq Vcc < 4.5V$	
			150	_	ns	$1.8V \leq Vcc < 2.5V$	
			100	_	ns	$4.5V \le Vcc \le 5.5V$	
3 Тсѕн		CS Hold Time	200	_	ns	$2.5V \leq Vcc < 4.5V$	
			250	_	ns	1.8V ≤ Vcc < 2.5V	
4	TCSD	CS Disable Time	50	-			
			10	_	ns	$4.5V \le Vcc \le 5.5V$	
5 Tsu		Data Setup Time	20		ns	2.5V ≤ Vcc < 4.5V	
		·	30	_	ns	1.8V ≤ Vcc < 2.5V	
		Data Hold Time	20		ns	4.5V ≤ Vcc ≤ 5.5V	
6	THD		40	_	ns	$2.5V \leq Vcc < 4.5V$	
			50	_	ns	1.8V ≤ Vcc < 2.5V	
7	TR	CLK Rise Time	—	100	ns	Note 1	
8	TF	CLK Fall Time	_	100	ns	Note 1	
			50	—	ns	$4.5V \leq Vcc \leq 5.5V$	
9	Тні	Clock High Time	100	_	ns	$2.5V \leq Vcc < 4.5V$	
			150	_	ns	$1.8V \leq Vcc < 2.5V$	
			50	—	ns	$4.5V \le Vcc \le 5.5V$	
10	) TLO Clock Low Time		100	_	ns	$2.5V \leq Vcc < 4.5V$	
			150	—	ns	$1.8V \leq Vcc < 2.5V$	
11	TCLD	Clock Delay Time	50	_	ns		
12	TCLE	Clock Enable Time	50	—	ns		
			—	50	ns	$4.5V \le Vcc \le 5.5V$	
13	Τv	Output Valid from Clock Low	—	100	ns	$2.5V \leq Vcc < 4.5V$	
			—	160	ns	$1.8V \leq Vcc < 2.5V$	
14	Тно	Output Hold Time	0	_	ns	Note 1	
			_	40	ns	$4.5V \le Vcc \le 5.5V$ (Note 1)	
15	TDIS	Output Disable Time		80	ns	$2.5V \le Vcc \le 4.5V$ (Note 1)	
			_	160	ns	$1.8V \le Vcc \le 2.5V$ (Note 1)	
			20	_	ns	$4.5V \le Vcc \le 5.5V$	
16	Tнs	HOLD Setup Time	40	_	ns	$2.5V \leq Vcc < 4.5V$	
			80	_	ns	1.8V ≤ Vcc < 2.5V	

#### TABLE 1-2: AC CHARACTERISTICS

Note 1: This parameter is periodically sampled and not 100% tested.

- 2: Twc begins on the rising edge of  $\overline{\text{CS}}$  after a valid write sequence and ends when the internal write cycle is complete.
- 3: This parameter is not tested but ensured by characterization.

AC CHA	RACTER	ISTICS	Industrial (I): $TA = -40^{\circ}C$ to $+85^{\circ}C$ Vcc = 1.8V to 5.5V Extended (E): $TA = -40^{\circ}C$ to $+125^{\circ}C$ Vcc = 1.8V to 5.5V				
Param. No.	Symbol	Characteristic	Minimum	Maximum	Units	Test Conditions	
				_	ns	$4.5V \leq Vcc \leq 5.5V$	
17	Тнн	HOLD Hold Time	40	_	ns	$2.5V \leq Vcc < 4.5V$	
			80	_	ns	$1.8V \leq Vcc < 2.5V$	
	Тнz	HOLD Low to Output High-Z	_	30	ns	$4.5V \le Vcc \le 5.5V$ (Note 1)	
18			_	60	ns	2.5V ≤ Vcc < 4.5V (Note 1)	
			_	160	ns	1.8V ≤ Vcc < 2.5V (Note 1)	
		HV HOLD High to Output Valid	_	30	ns	$4.5V \le Vcc \le 5.5V$	
19	THV		_	60	ns	$2.5V \leq Vcc < 4.5V$	
			_	160	ns	$1.8V \leq Vcc < 2.5V$	
20	Twc	Internal Write Cycle Time		5	ms	Note 2	
21		Endurance	1M	_	E/W Cycles	+25°C, Vcc = 5.5V (Note 3)	

#### TABLE 1-2:AC CHARACTERISTICS (CONTINUED)

**Note 1:** This parameter is periodically sampled and not 100% tested.

2: Twc begins on the rising edge of  $\overline{\text{CS}}$  after a valid write sequence and ends when the internal write cycle is complete.

3: This parameter is not tested but ensured by characterization.

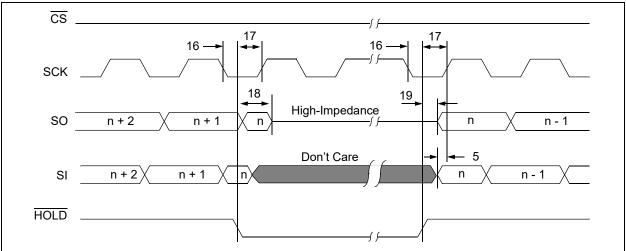
#### TABLE 1-3: AC TEST CONDITIONS

AC Waveform				
VLO = 0.2V				
VHI = VCC - 0.2V	Note 1			
VHI = 4.0V	Note 2			
C∟ = 50 pF	—			
Timing Measurement Reference I	_evel			
Input	0.5 Vcc			
Output	0.5 Vcc			

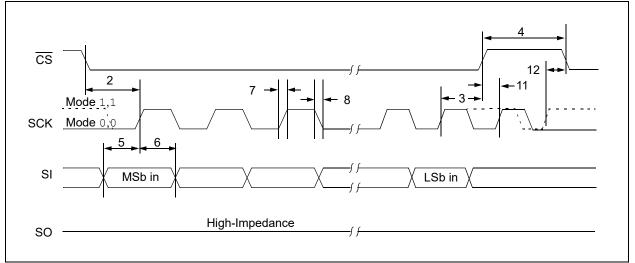
Note 1: For VCC  $\leq 4.0V$ 

2: For Vcc > 4.0V

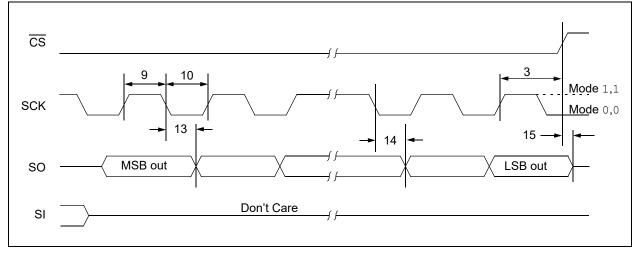
#### FIGURE 1-1: HOLD TIMING



#### FIGURE 1-2: SERIAL INPUT TIMING



#### FIGURE 1-3: SERIAL OUTPUT TIMING



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# 2.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 2-1.

Name	DFN-S <sup>(1)</sup>	PDIP	SOIC	TSSOP	Rotated TSSOP	Function
CS	1	1	1	1	3	Chip Select Input
SO	2	2	2	2	4	Serial Data Output
WP	3	3	3	3	5	Write-Protect Pin
Vss	4	4	4	4	6	Ground
SI	5	5	5	5	7	Serial Data Input
SCK	6	6	6	6	8	Serial Clock Input
HOLD	7	7	7	7	1	Hold Input
Vcc	8	8	8	8	2	Supply Voltage

#### TABLE 2-1: PIN FUNCTION TABLE

Note 1: Exposed pad on DFN-S package can be connected to Vss or left floating.

# 2.1 Chip Select (CS)

A low level on this pin selects the device. A high level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated or in progress will be completed, regardless of the  $\overline{CS}$  input signal. If  $\overline{CS}$  is brought high during a program cycle, the device will go into Standby mode as soon as the programming cycle is complete. When the device is deselected, SO goes to the high-impedance state, allowing multiple parts to share the same SPI bus. A low-to-high transition on  $\overline{CS}$  after a valid write sequence initiates an internal write cycle. After power-up, a low level on  $\overline{CS}$  is required prior to any sequence being initiated.

# 2.2 Serial Output (SO)

The SO pin is used to transfer data out of the 25XX256. During a read cycle, data are shifted out on this pin after the falling edge of the serial clock.

# 2.3 Write-Protect (WP)

This pin is used in conjunction with the WPEN bit in the STATUS register to prohibit writes to the nonvolatile bits in the STATUS register. When WP is low and WPEN is high, writing to the nonvolatile bits in the STATUS register is disabled. All other operations function normally. When  $\overline{WP}$  is high, all functions, including writes to the nonvolatile bits in the STATUS register, operate normally. If the WPEN bit is set, WP low during a STATUS register write sequence will disable writing to the STATUS register. If an internal write cycle has already begun, WP going low will have no effect on the write. The WP pin function is blocked when the WPEN bit in the STATUS register is low. This allows the user to install the 25XX256 in a system with WP pin grounded and still be able to write to the STA-TUS register. The WP pin functions will be enabled when the WPEN bit is set high.

# 2.4 Serial Input (SI)

The SI pin is used to transfer data into the device. It receives instructions, addresses and data. Data are latched on the rising edge of the serial clock.

# 2.5 Serial Clock (SCK)

The SCK is used to synchronize the communication between a host and the 25XX256. Instructions, addresses or data present on the SI pin are latched on the rising edge of the clock input, while data on the SO pin is updated after the falling edge of the clock input.

# 2.6 Hold (HOLD)

The HOLD pin is used to suspend transmission to the 25XX256 while in the middle of a serial sequence without having to retransmit the entire sequence again. It must be held high any time this function is not being used. Once the device is selected and a serial sequence is underway, the HOLD pin may be pulled low to pause further serial communication without resetting the serial sequence. The HOLD pin must be brought low while SCK is low, otherwise the HOLD function will not be invoked until the next SCK high-to-low transition. The 25XX256 must remain selected during this sequence. The SI and SCK levels are "don't cares" during the time the device is paused and any transitions on these pins will be ignored. To resume serial communication, HOLD must be brought high while the SCK pin is low, otherwise serial communication will not be resumed until the next SCK high-to-low transition.

The SO line will tri-state immediately upon a high-to-low transition of the HOLD pin and will begin outputting again immediately upon a subsequent low-to-high transition of the HOLD pin, independent of the state of SCK.

# 3.0 FUNCTIONAL DESCRIPTION

# 3.1 Principles of Operation

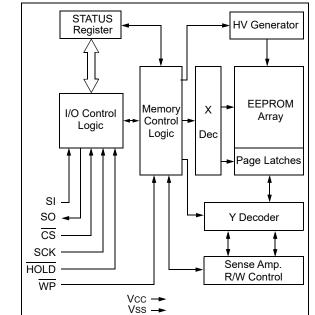
The 25XX256 is a 32,768-byte Serial EEPROM designed to interface directly with the Serial Peripheral Interface (SPI) port of many of today's popular micro controller families, including Microchip's PIC<sup>®</sup> micro-controllers. It may also interface with microcontrollers that do not have a built-in SPI port by using discrete I/O lines programmed properly in firmware to match the SPI protocol.

The 25XX256 contains an 8-bit instruction register. The device is accessed via the SI pin, with data being clocked in on the rising edge of SCK. The CS pin must be low and the HOLD pin must be high for the entire operation.

Table 3-1 contains a list of the possible instruction bytes and format for device operation. All instructions, addresses and data are transferred MSb first, LSb last.

Data <u>(SI)</u> are sampled on the first rising edge of SCK after CS goes low. If the clock line is shared with other peripheral devices on the SPI bus, the user can assert the HOLD input and place the 25XX256 in HOLD mode. After releasing the HOLD pin, operation will resume from the point when the HOLD was asserted.

#### TABLE 3-1: INSTRUCTION SET



Instruction Name	Instruction Format	Description
READ	0000 0011	Read data from memory array beginning at selected address
WRITE	0000 0010	Write data to memory array beginning at selected address
WRDI	0000 0100	Reset the write enable latch (disable write operations)
WREN	0000 0110	Set the write enable latch (enable write operations)
RDSR	0000 0101	Read STATUS register
WRSR	0000 0001	Write STATUS register

# **BLOCK DIAGRAM**

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#### 3.2 Read Sequence

The device is selected by pulling  $\overline{CS}$  low. The 8-bit READ instruction is transmitted to the 25XX256 followed by the 16-bit address, with the first MSb of the address being a "don't care" bit. After the correct READ instruction and address are sent, the data stored in the memory at the selected address are shifted out on the SO pin. The data stored in the memory at the next address can be read sequentially by continuing to provide clock pulses. The internal Address Pointer is automatically incremented to the next higher address after each byte of data is shifted out. When the highest address is reached (7FFFh), the address counter rolls over to address 0000h allowing the read cycle to be continued indefinitely. The read operation is terminated by raising the  $\overline{CS}$  pin (Figure 3-1).

#### 3.3 Write Sequence

Prior to any attempt to write data to the 25XX256, the write enable latch must be set by issuing the <u>WREN</u> instruction (Figure 3-4). This is done by setting CS low and then clocking out the proper instruction into the 25XX256. After <u>all</u> eight bits of the instruction are transmitted, the CS must be brought high to set the write enable latch. If the write operation is initiated immediately after the <u>WREN</u> instruction without CS being brought high, the data will not be written to the array because the write enable latch will not have been properly set.

Once the write enable latch is set, the user may proceed by setting the  $\overline{CS}$  low, issuing a WRITE instruction, followed by the 16-bit address, with the first MSb of the address being a "don't care" bit and then the data to be written. Up to 64 bytes of data can be sent to the device before a write cycle is necessary. The only restriction is that all of the bytes must reside in the same page.

Note: Page write operations are limited to writing bytes within a single physical page, regardless of the number of bytes actually being written. Physical page boundaries start at addresses that are integer multiples of the page buffer size (or 'page size') and, end at addresses that are integer multiples of page size – 1. If a page write command attempts to write across a physical page boundary, the result is that the data wraps around to the beginning of the current page (overwriting data previously stored there), instead of being written to the next page as might be expected. It is therefore necessary for the application software to prevent page write operations that would attempt to cross a page boundary.

For the data to be actually written to the array, the  $\overline{CS}$  must be brought high after the Least Significant bit (D0) of the *n*<sup>th</sup> data byte has been clocked in. If  $\overline{CS}$  is brought high at any other time, the write operation will not be completed. Refer to Figure 3-2 and Figure 3-3 for more detailed illustrations on the byte write sequence and the page write sequence, respectively. While the write is in progress, the STATUS register may be read to check the status of the Write-In-Process (WIP) bit (Figure 3-6). A read attempt of a memory array location will not be possible during a write cycle. When the write cycle is completed, the write enable latch is reset.

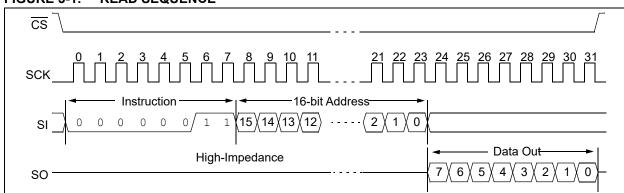
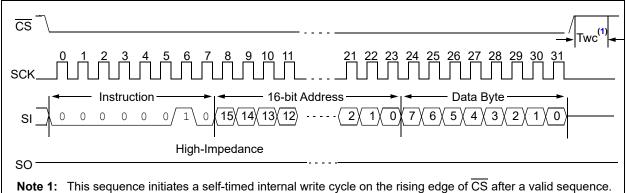
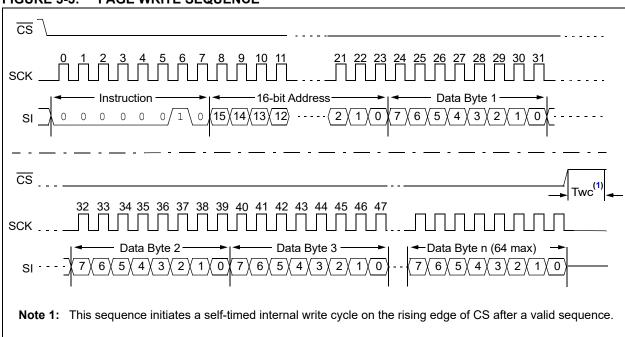


FIGURE 3-1: READ SEQUENCE







#### FIGURE 3-3: PAGE WRITE SEQUENCE

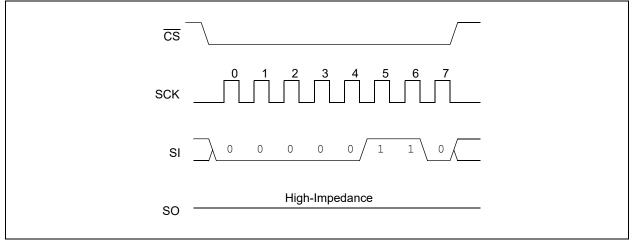
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# 3.4 Write Enable (WREN) and Write Disable (WRDI)

The 25XX256 contains a write enable latch. See Table 5-1 for the Write-Protect Functionality Matrix. This latch must be set before any write operation will be completed internally. The WREN instruction will set the latch and the WRDI will reset the latch.

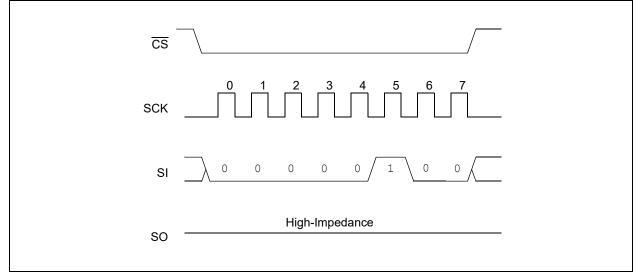
The following is a list of conditions under which the write enable latch will be reset:

- Power-up
- WRDI instruction successfully executed
- WRSR instruction successfully executed
- WRITE instruction successfully executed



#### FIGURE 3-4: WRITE ENABLE SEQUENCE (WREN)





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# 3.5 Read STATUS Register Instruction (RDSR)

The Read STATUS Register instruction (RDSR) pr ovides access to the STATUS register. The STATUS register may be read at any time, even during a write cycle. The STATUS register is formatted as follows:

<b>TABLE 3-2</b> :	STATUS REGISTER
--------------------	-----------------

7	6	5	4	3	2	1	0
W/R	-	-	-	W/R	W/R	R	R
WPEN	х	х	х	BP1	BP0	WEL	WIP

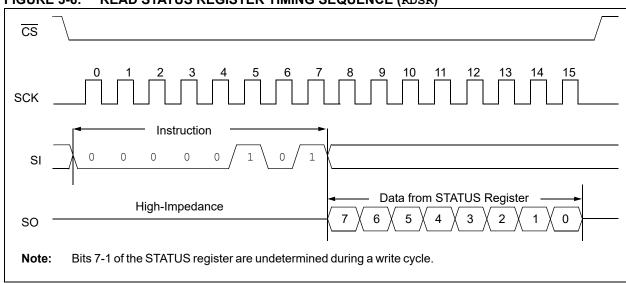
**Note 1:** W/R = writable/readable. R = read-only.

The **Write-In-Process (WIP)** bit indicates whether the 25XX256 is busy with a write operation. When set to a '1', a write is in progress, when set to a '0', no write is in progress. This bit is read-only.

The **Write Enable Latch (WEL)** bit indicates the STATUS of the write enable latch and is read-only. When set to a '1', the latch allows writes to the array, when set to a '0', the latch prohibits writes to the array. The state of this bit can always be updated via the WREN or WRDI commands, regardless of the state of write protection on the STATUS register. These commands are shown in Figure 3-4 and Figure 3-5.

The **Block Protection (BP0 and BP1)** bits indicate which blocks are currently write-protected. These bits are set by the user issuing the WRSR instruction. These bits are nonvolatile and are shown in Table 3-3.

See Figure 3-6 for the RDSR timing sequence.





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# 3.6 Write STATUS Register Instruction (WRSR)

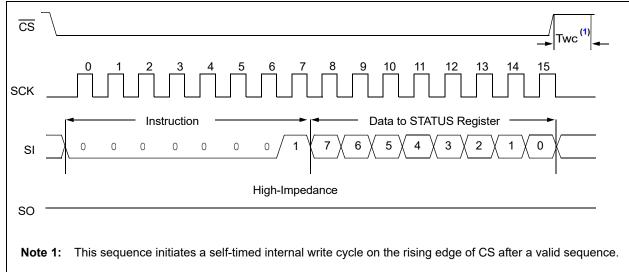
The Write STATUS Register instruction (WRSR) allows the user to write to the nonvolatile bits in the STATUS register as shown in Table 3-2. The user is able to select one of four levels of protection for the array by writing to the appropriate bits in the STATUS register. The array is divided up into four segments. The user has the ability to write-protect none, one, two or all four of the segments of the array. The partitioning is controlled as shown in Table 3-3.

The Write-Protect Enable (WPEN) bit is a nonvolatile bit that is available as an enable bit for the WP pin. The Write-Protect (WP) pin and the Write-Protect Enable (WPEN) bit in the STATUS register control the programmable hardware write-protect feature. Hardware write protection is enabled when WP pin is low and the WPEN bit is high. Hardware write protection is disabled when either the WP pin is high or the WPEN bit is low. When the chip is hardware Write-Protected, only writes to nonvolatile bits in the STATUS register are disabled. See Table 5-1 for a matrix of functionality on the WPEN bit. See Figure 3-7 for the WRSR timing sequence.

TABLE 3-3:	<b>ARRAY PROTECTION</b>
------------	-------------------------

BP1	BP0	Array Addresses Write Protected
0	0	none
0	1	upper 1/4 (6000h-7FFFh)
1	0	upper 1/2 (4000h-7FFFh)
1	1	all (0000h-7FFFh)





# 4.0 DATA PROTECTION

The following protection has been implemented to prevent inadvertent writes to the array:

- The write enable latch is reset on power-up
- A write enable instruction must be issued to set the write enable latch
- After a byte write, page write or STATUS register write, the write enable latch is reset
- CS must be set high after the proper number of clock cycles to start an internal write cycle
- Access to the array during an internal write cycle is ignored and programming is continued

# 5.0 POWER-ON STATE

The 25XX256 powers on in the following state:

- The device is in low-power Standby Mode  $(\overline{CS} = 1)$
- · The write enable latch is reset
- SO is in high-impedance state
- A high-to-low-level transition on cs is required to enter active state

WEL (SR bit 1)	WPEN (SR bit 7)	WP pin	Protected Blocks	Unprotected Blocks	STATUS Register
0	х	х	Protected	Protected	Protected
1	0	X	Protected	Writable	Writable
1	1	0 (low)	Protected	Writable	Protected
1	1	1 (high)	Protected	Writable	Writable

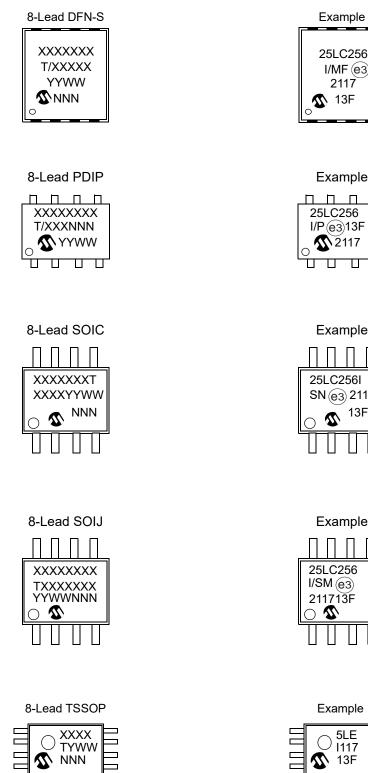
#### TABLE 5-1: WRITE-PROTECT FUNCTIONALITY MATRIX

**Note 1:** x = don't care

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#### 6.0 PACKAGING INFORMATION

#### 6.1 **Package Marking Information**



25LC256 I/MF (e3)

Example





Example							
25LC256	1						
I/SM (e3)							
211713F							

#### Example

○ 5LE	]
1117	]
☎ 13F	]

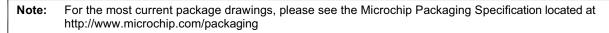
DS20001822J-page 14

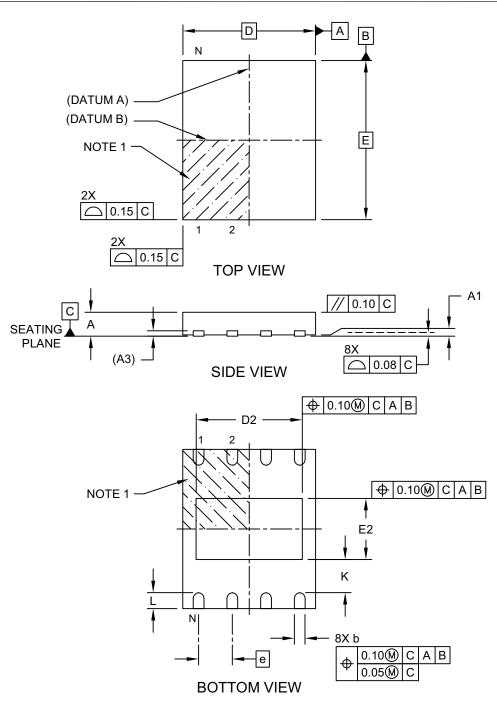
	1 <sup>st</sup> Line Marking Codes								
Device DFN-S PDIP SOIC SOIJ TSSOP Rotated TSS									
25AA256	25AA256	25AA256	25AA256T	25AA256	5AE	5AEX			
25LC256	25LC256	25LC256	25LC256T	25LC256	5LE	5LEX			

Legend	I: XXX	Part number or part number code
	I	Temperature (I, E)
	Y	Year code (last digit of calendar year)
	YY	Year code (last 2 digits of calendar year)
	WW	Week code (week of January 1 is week '01')
	NNN	Alphanumeric traceability code (2 characters for small packages)
	(e3)	RoHS-compliant JEDEC designator for Matte Tin (Sn)
Note:		small packages with no room for the RoHS-compliant JEDEC
	designato	r $(\underline{e3})$ , the marking will only appear on the outer carton or reel label.
Note:	be carrie	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available s for customer-specific information.

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# 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

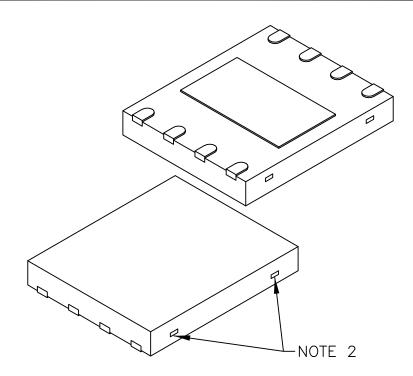




Microchip Technology Drawing C04-122 Rev C Sheet 1 of 2

#### 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	Dimension Limits		NOM	MAX
Number of Terminals	N		8	
Pitch	е		1.27 BSC	
Overall Height	Α	0.80	0.85	1.00
Standoff	A1	0.00	0.02	0.05
Terminal Thickness	A3	0.20 REF		
Overall Length	D	5.00 BSC		
Exposed Pad Length	D2	3.90	4.00	4.10
Overall Width	E		6.00 BSC	
Exposed Pad Width	E2	2.20	2.30	2.40
Terminal Width	b	0.30	0.40	0.50
Terminal Length	L	0.50	0.60	0.75
Terminal-to-Exposed-Pad	К	0.20	-	-

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

- 2. Package may have one ore more exposed tie bars at ends.
- 3. Package is saw singulated
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

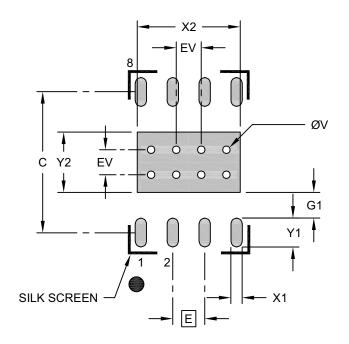
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-122 Rev C Sheet 2 of 2

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# 8-Lead Plastic Dual Flat, No Lead Package (MF) - 6x5 mm Body [DFN-S] Saw Singulated

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



# RECOMMENDED LAND PATTERN

	Ν	<b>/ILLIMETER</b>	S	
Dimension	Dimension Limits			MAX
Contact Pitch	E		1.27 BSC	
Optional Center Pad Width	X2			2.40
Optional Center Pad Length	Y2			4.10
Contact Pad Spacing	С		5.60	
Contact Pad Width (X20)	X1			0.45
Contact Pad Length (X20)	Y1			1.15
Contact Pad to Center Pad (X20)	G1	0.20		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

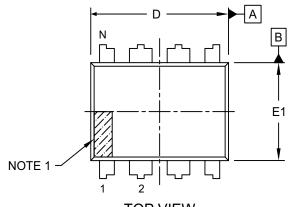
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

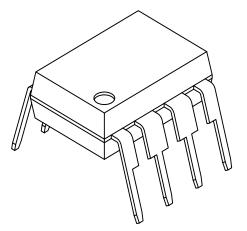
Microchip Technology Drawing C04-2122 Rev C

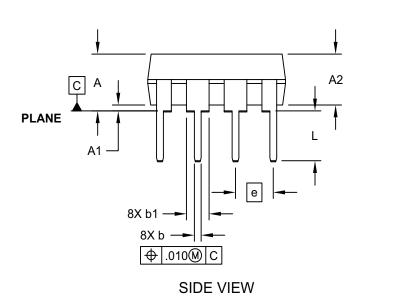
# 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

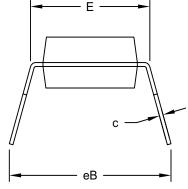
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging











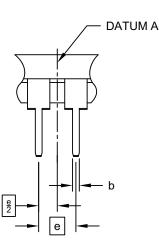
**END VIEW** 

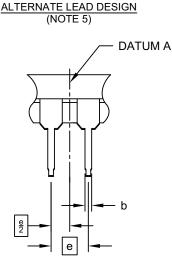
Microchip Technology Drawing No. C04-018-P Rev E Sheet 1 of 2

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#### 8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





Units		INCHES		
Dimension	Dimension Limits		NOM	MAX
Number of Pins	N		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	Е	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	С	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eВ	-	-	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

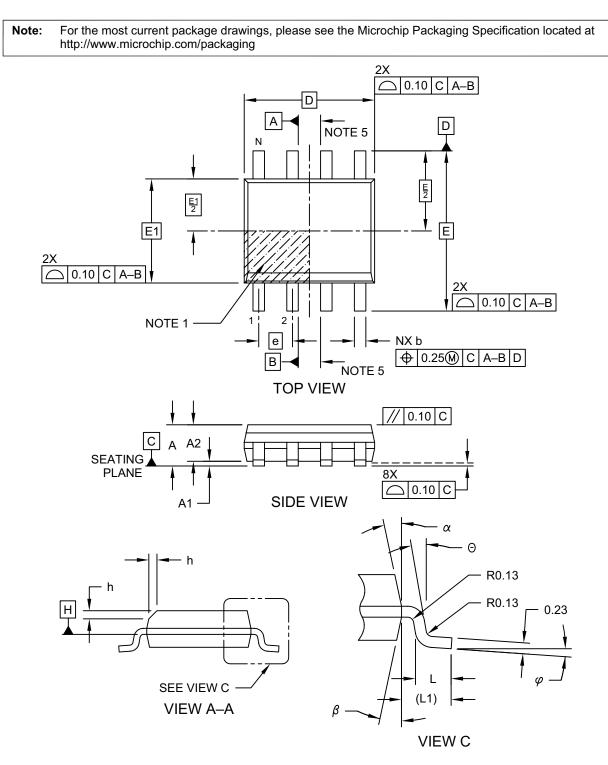
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

5. Lead design above seating plane may vary, based on assembly vendor.

Microchip Technology Drawing No. C04-018-P Rev E Sheet 2 of 2

# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

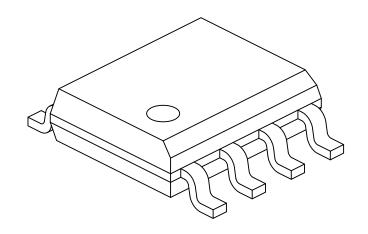


Microchip Technology Drawing No. C04-057-SN Rev F Sheet 1 of 2

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# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		1.27 BSC	
Overall Height	Α	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E	6.00 BSC		
Molded Package Width	E1	3.90 BSC		
Overall Length	D	4.90 BSC		
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1		1.04 REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.17	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

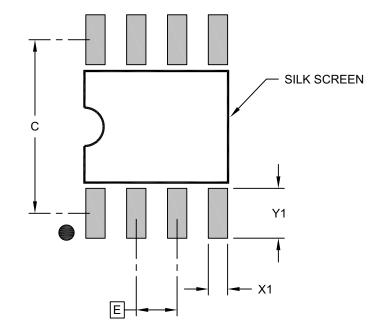
BSC: Basic Dimension. Theoretically exact value shown without tolerances. REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev F Sheet 2 of 2

# 8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



# RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

#### Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

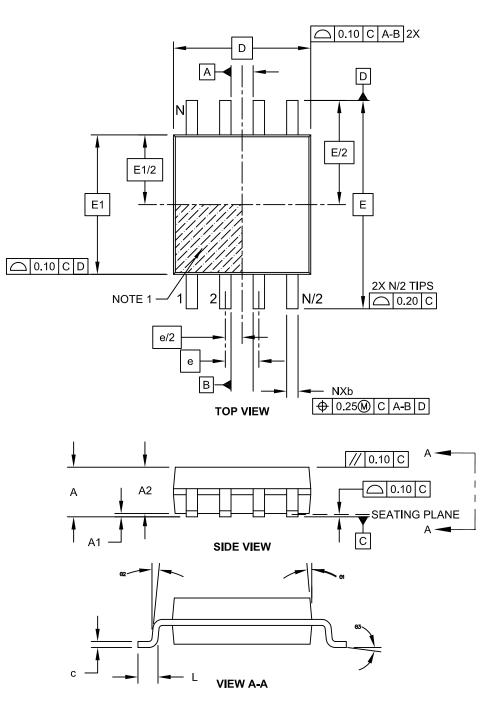
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev F

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#### 8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

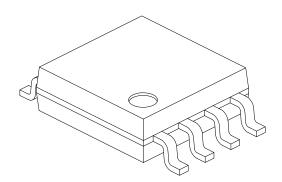
**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



Microchip Technology Drawing C04-056C Sheet 1 of 2

# 8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		1.27 BSC	
Overall Height	A	1.77	-	2.03
Standoff §	A1	0.05		0.25
Molded Package Thickness	A2	1.75	-	1.98
Overall Width	Ш	7.94 BSC		
Molded Package Width	E1	5.25 BSC		
Overall Length	D		5.26 BSC	
Foot Length	L	0.51	-	0.76
Lead Thickness	С	0.15	-	0.25
Lead Width	b	0.36	-	0.51
Mold Draft Angle	Θ1	-	-	15°
Lead Angle	Θ2	0°	-	8°
Foot Angle	Θ3	0°	-	8°

Notes:

1. SOIJ, JEITA/EIAJ Standard, Formerly called SOIC

2. § Significant Characteristic

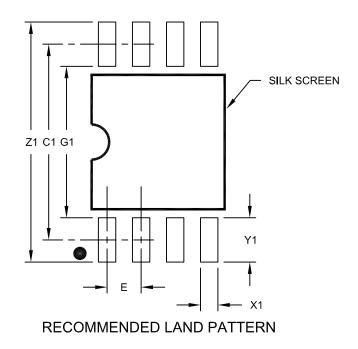
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.

Microchip Technology Drawing No. C04-056C Sheet 2 of 2

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8-Lead Plastic Small Outline (SM) - Medium, 5.28 mm Body [SOIJ]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			S	
Dimens	Dimension Limits		NOM	MAX	
Contact Pitch	Contact Pitch E		1.27 BSC		
Overall Width	Z1			9.00	
Contact Pad Spacing	C1		7.30		
Contact Pad Width (X8) X1				0.65	
Contact Pad Length (X8)	Y1			1.70	
Distance Between Pads	G1	5.60			
Distance Between Pads	G	0.62			

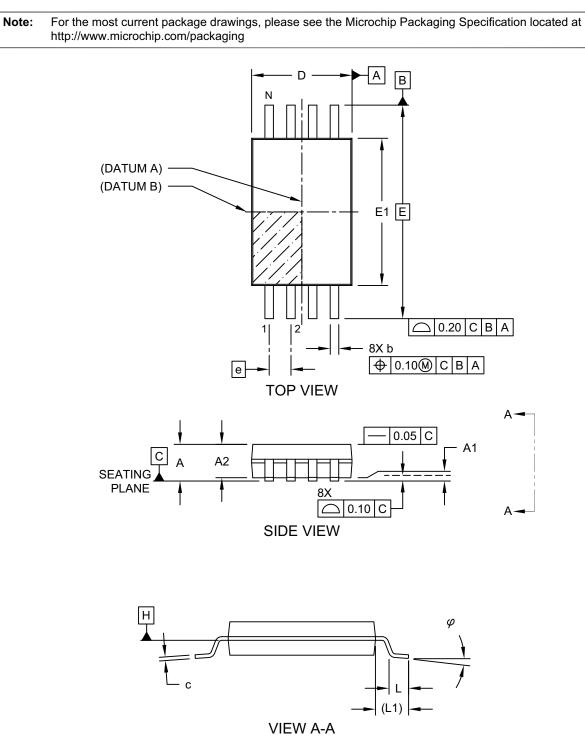
Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2056C

# 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

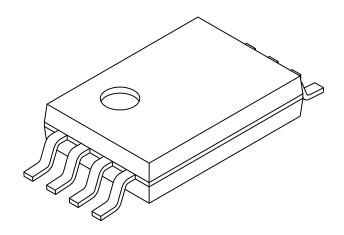


Microchip Technology Drawing C04-086 Rev C Sheet 1 of 2

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# 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Number of Pins	N		8	
Pitch	е		0.65 BSC	
Overall Height	Α	-	-	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	-	-
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Overall Length	D	2.90	3.00	3.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1	1.00 REF		
Lead Thickness	С	0.09	-	0.25
Foot Angle	φ	0°	4°	8°
Lead Width	b	0.19	-	0.30

Notes:

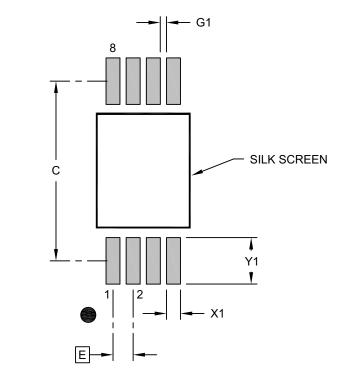
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.20mm per side.
- 3. Dimensioning and tolerancing per ASME Y14.5M
  - BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086 Rev C Sheet 2 of 2

# 8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



# RECOMMENDED LAND PATTERN

	MILLIMETERS			
Dimension	MIN	NOM	MAX	
Contact Pitch	Е		0.65 BSC	
Contact Pad Spacing	С		5.80	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.50
Contact Pad to Center Pad (X6)	G1	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-2086 Rev B

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# APPENDIX A: REVISION HISTORY

#### Revision J (07/2021)

Added Automotive Product ID section; Replaced "master" and "slave" terminology with "host" and "client", respectively; Updated DFN-S, SOIC and TSSOP package drawings; Reformatted some sections for better readability.

# Revision H (08/2019)

Revise Product ID System, packages and notes; Clarified Extended E-Temp description; Update RoHS compliant description; Update PDIP package drawing.

# **Revision G (01/2013)**

Revise Automotive E Temp; Revise Table 1-2, Param. No. 21.

# Revision F (05/07)

Update Pb-free; Replace Package Drawings (Rev. AP); Update Product ID section.

# Revision E (08/05)

Remove Preliminary status. Revise Table 1-1, Params. D011 and D012.

# Revision D (06/05)

Update package information

# Revision C (11/03)

Corrections to Section 1.0, Electrical Characteristics.

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# **PRODUCT IDENTIFICATION SYSTEM (NON-AUTOMOTIVE)**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	IXI <sup>(1)</sup> -X /XX Tape and Reel Temperature Package Option Range	Examples: a) 25AA256T-I/SN: 256 Kbit, 1.8V Serial EEPROM, Industrial temperature, Tape and Reel, SOIC package
Device: Tape and Reel Option:	25AA256:256 Kbit, 1.8V, 64-Byte Page, SPI Serial EEPROM25LC256:256 Kbit, 2.5V, 64-Byte Page, SPI Serial EEPROM25AA256X:256 Kbit, 1.8V, 64-Byte Page, SPI Serial EEPROM, in alternate pinout (ST only)25LC256X:256 Kbit, 2.5V, 64-Byte Page, SPI Serial EEPROM, in alternate pinout (ST only)Blank =Standard packaging (tube) TT=Tape and Reel	<ul> <li>b) 25AA256T-I/ST: 256 Kbit, 1.8V Serial EEPROM, Industrial temperature, Tape and Reel, TSSOP package</li> <li>c) 25LC256-I/P: 256 Kbit, 2.5V Serial EEPROM, Industrial temperature, PDIP package</li> <li>d) 25LC256T-E/ST: 256 Kbit, 2.5V Serial EEPROM, Extended temperature, Tape and Reel, TSSOP package</li> <li>e) 25LC256XT-I/ST: 256 Kbit, 2.5V Serial EEPROM, Industrial temperature, Tape and Reel, Alternate pinout, TSSOP package</li> <li>f) 25AA256T-E/SM: 256 Kbit, 1.8V Serial</li> </ul>
Temperature Range:	I = $-40^{\circ}$ C to $+85^{\circ}$ C (Industrial) E = $-40^{\circ}$ C to $+125^{\circ}$ C (Extended)	EEPROM, Extended temperature, Tape
Package:	<ul> <li>MF = Plastic Micro Lead Frame (6 x 5 mm body), 8-lead (DFN-S)</li> <li>P = Plastic Dual In-Line - 300 mil Body, 8-lead (PDIP)</li> <li>SN = Plastic Small Outline - Narrow, 3.90 mm Body, 8-lead (SOIC)</li> <li>SM = Plastic Small Outline - Wide, 5.28 mm Body, 8-lead (SOIJ)</li> <li>ST = Plastic Thin Shrink Small Outline - 4.4 mm, 8-lead (TSSOP)</li> </ul>	Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes only and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

# **PRODUCT IDENTIFICATION SYSTEM (AUTOMOTIVE)**

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

PART NO.	<u>[X]</u> <sup>(1)</sup>	<u>-X</u>	<u>/XX</u>	<u>xxx</u> <sup>(2,3)</sup>	Exa	imples:		
Device	Tape and Reel Option	Temperature Range	Package	Variant	a)	25AA256T-I/SN16KVAO: 256 Kbit, 1.8V Serial EEPROM, Automotive Grade 3, Tape and Reel, SOIC package		
Device:	25AA256: 25LC256:	256 Kbit, 1.8V, EEPROM 256 Kbit, 2.5V, EEPROM	, ,		b) c)	25AA256T-I/ST16KVAO:, 256 Kbit, 1.8V Serial EEPROM, Automotive Grade 3, Tape and Reel, TSSOP package 25LC256-E/SN16KVAO: 256 Kbit, 2.5V Serial EEPROM, Automotive Grade 1, SOIC package		
Tape and Ree Option:	I Blank = Sta T = Tap	ndard packagin e and Reel <sup>(1)</sup>	g (tube)		d) e)	25LC256T-E/ST16KVAO: 256 Kbit, 2.5V Serial EEPROM, Automotive Grade 1, Tape and Reel, Rotated TSSOP package 25LC256T-E/SM16KVAO: 256 Kbit, 2.5V		
Temperature Range:		°C to +85°C (A °C to +125°C (A		,	6)	Serial EEPROM, Automotive Grade 1, Tape and Reel, SOIJ package		
Package:	Bo SM = Pla Bo ST = Pla	astic Small Outl ody, 8-lead (SOI astic Small Outl ody, 8-lead (SOI astic Thin Shrink ead (TSSOP)	C) ine - Wide, 5 J)	.28 mm	No	te 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes only and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.		
Variant <sup>(2,3)</sup> :	16KVAO =	Standard Autor Customer-Spe Process	,			<ol> <li>The VAO/VXX automotive variants have been designed, manufactured, tested and qualified in accordance with AEC-Q100 requirements for automotive applications.</li> </ol>		
						<b>3:</b> For customers requesting a PPAP, a customer-specific part will be generated and provided. A PPAP is not provided for VAO part numbers.		

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ISBN: 978-1-5224-8501-8

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